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Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

Office Action Summary	Application No. 10/684,939	Applicant(s) MABUCHI, KEIJI
	Examiner JOHN C. INGHAM	Art Unit 2814

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --
Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If no period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED. (35 U.S.C. § 133).

Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

1) Responsive to communication(s) filed on 07 July 2008.
 2a) This action is FINAL. 2b) This action is non-final.
 3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

4) Claim(s) 1,2,4-9,16,17 and 19-33 is/are pending in the application.
 4a) Of the above claim(s) _____ is/are withdrawn from consideration.
 5) Claim(s) _____ is/are allowed.
 6) Claim(s) 1,2,4-9,16,17 and 19-33 is/are rejected.
 7) Claim(s) _____ is/are objected to.
 8) Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

9) The specification is objected to by the Examiner.
 10) The drawing(s) filed on 13 June 2007 is/are: a) accepted or b) objected to by the Examiner.
 Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
 Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
 11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
 a) All b) Some * c) None of:
 1. Certified copies of the priority documents have been received.
 2. Certified copies of the priority documents have been received in Application No. _____.
 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

* See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

1) Notice of References Cited (PTO-892)
 2) Notice of Draftsperson's Patent Drawing Review (PTO-948)
 3) Information Disclosure Statement(s) (PTO/SB/08)
 Paper No(s)/Mail Date 4/10/08

4) Interview Summary (PTO-413)
 Paper No(s)/Mail Date _____
 5) Notice of Informal Patent Application
 6) Other: _____

DETAILED ACTION

1. The amendments filed 7 July 2008 have been entered. The objection to claim 16 has been withdrawn.

Claim Rejections - 35 USC § 102

2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless –

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

3. Claims 1, 2, 4-8, 16, 17, 19-23 and 27-33 are rejected under 35 U.S.C. 102(e) as being anticipated by Fox (US 6,566,697).

4. Regarding claims 1 and 16, Fox discloses in Fig 1 a camera apparatus for outputting an image taken by a solid-state imaging device (col 2 ln 1-6), the camera apparatus comprising: the solid-state imaging device having an imaging region section (10) provided with a plurality of pixels and a processing circuit section for processing an image signal outputted from the imaging region section (col 1 ln 20-30), the solid-state imaging device comprising: each pixel having a photoelectric converting element (12) for generating a signal charge commensurate with a light-receiving amount, a floating diffusion part (18) for detecting an amount of a signal charge generated by the photoelectric converting element, a transfer transistor (16) for transferring a signal charge generated by the photoelectric converting element to the floating diffusion part, and a drain transistor (22) for draining a signal charge generated by the photoelectric

converting element; wherein the photoelectric converting element comprises a buried photodiode (Fig 8) having a charge separating region comprising a first conductivity type high-concentration impurity layer (Fig 8 item p) in an extreme surface of a semiconductor substrate and a charge storing region comprising a second conductivity type impurity layer (Fig 8 item n) in a layer beneath the charge separating region; both a channel potential on the drain transistor being turned on and a channel potential on the transfer transistor being turned on are set higher than a potential for depleting the photodiode (Fig 3B for transfer, Fig 3F for drain).

5. In reference to the claim language reciting that both a gate electrode of the drain transistor being turned off and a gate electrode of the transfer transistor being turned off are biased with a prescribed voltage to form a first conductivity type channel layer at an interface of a gate insulation film of each transistor, intended use and other types of functional language must result in a structural difference between the claimed invention and the prior art in order to patentably distinguish the claimed invention from the prior art. If the prior art structure is capable of performing the intended use, then it meets the claim. In a claim drawn to a process of making, the intended use must result in a manipulative difference as compared to the prior art. In re Casey, 152 USPQ 235 (CCPA 1967); In re Otto, 136 USPQ 458, 459 (CCPA 1963).

6. In this case, the transfer transistor (16) and drain transistor (22) have gate nodes (TCK and EC, respectively) that may be biased with a negative voltage to form a first conductivity type channel layer at an interface of a gate insulating film of each transistor.

7. Regarding claims **2 and 17**, Fox discloses in Fig 1 the device of claims 1 and 16, further having a reset transistor (20) for resetting the floating diffusion part with a signal charge, and an amplifying transistor (24) for outputting an electric signal corresponding to a potential on the floating diffusion part, and a selecting transistor (28) for selectively activating the amplifying transistor.

8. With regards to claims **4 and 19**, Fox discloses in Fig 1 the device of claims 1 and 16. The claim language referring to the simultaneous resetting, simultaneous signal transfer, row by row signal read-out, and the fact that the drain transistor is kept on until the reading operation proceeds to a predetermined row, describes an intended use of the device. Intended use and other types of functional language must result in a structural difference between the claimed invention and the prior art in order to patentably distinguish the claimed invention from the prior art. If the prior art structure is capable of performing the intended use, then it meets the claim. *In re Casey*, 152 USPQ 235 (CCPA 1967); *In re Otto*, 136 USPQ 458, 459 (CCPA 1963).

9. With regards to claims **5 and 20**, Fox discloses in Fig 1 the device of claims 4 and 19 wherein the photodiode, when substantially depleted, includes no charges (col 1 In 15-17) after readout or reset.

10. Regarding claims **6-8 and 21-23**, Fox discloses the device of claim 4 and 19. In reference to the claim language referring to the voltage applied to the gates of the individual transistors, and that the drain transistor is off during a read operation, intended use and other types of functional language must result in a structural difference between the claimed invention and the prior art in order to patentably

distinguish the claimed invention from the prior art. If the prior art structure is capable of performing the intended use, then it meets the claim. *In re Casey*, 152 USPQ 235 (CCPA 1967); *In re Otto*, 136 USPQ 458, 459 (CCPA 1963).

11. Regarding claims 27 and 30, Fox discloses in Fig 1 a solid-state imaging device comprising: a plurality of pixels (Fig 4); each pixels having a light-receiving part (12), a transfer transistor (16) for substantially depleting (col 1 ln 15-17) the charge storage region included in the light-receiving part and reading out a charge generated in the light-receiving part and a drain transistor (22) for draining the charge generated in the light-receiving part, wherein the light-receiving part has a charge storing region (14) with a potential increasing as the stored charge decreases during reading out charges and during draining charges (Fig 3) but lower than a potential on a channel part in a state the transfer transistor is on and a potential on the channel part in a state the drain transistor is on when the charge storing region is substantially depleted.

12. In reference to the claim language reciting that both a gate electrode of the drain transistor being turned off and a gate electrode of the transfer transistor being turned off are biased with a prescribed voltage to form a first conductivity type channel layer at an interface of a gate insulation film of each transistor, intended use and other types of functional language must result in a structural difference between the claimed invention and the prior art in order to patentably distinguish the claimed invention from the prior art. If the prior art structure is capable of performing the intended use, then it meets the claim. In a claim drawn to a process of making, the intended use must result in a

manipulative difference as compared to the prior art. In re Casey,152 USPQ 235 (CCPA 1967); In re Otto , 136 USPQ 458, 459 (CCPA 1963).

13. In this case, the transfer transistor (16) and drain transistor (22) have gate nodes (TCK and EC, respectively) that may be biased with a negative voltage in order to suppress current flow from said photodiode when no light is present.

14. With regards to claims **28 and 31**, Fox discloses in Fig 1 the device of claims 27 and 30 wherein the charge storing region, when substantially depleted, includes no charges (col 1 ln 15-17).

15. Regarding claim **29**, Fox discloses in Fig 1 the device of claim 27, wherein the pixel further has a charge holding part (18) for holding a charge read out by the transfer transistor (16). In reference to the claim language referring to the charge being read simultaneously on all the pixels, the charge being read out in a predetermined order, and the pixels being drained by the drain transistors to start an exposure time period, intended use and other types of functional language must result in a structural difference between the claimed invention and the prior art in order to patentably distinguish the claimed invention from the prior art. If the prior art structure is capable of performing the intended use, then it meets the claim. In re Casey,152 USPQ 235 (CCPA 1967); In re Otto , 136 USPQ 458, 459 (CCPA 1963). In this case, a row of the pixel structures of Fox is capable of being read simultaneously, or in a predetermined order, and the drain transistor voids the pixel of unwanted charge (col 1 ln 15-17).

16. Regarding claims **32 and 33**, Fox discloses in Fig 1 a solid-state imaging device (col 2 ln 1-6) having an imaging region section (10) provided with a plurality of pixels

and a processing circuit section for processing an image signal outputted from the imaging region section (col 1 ln 20-30), the solid-state imaging device comprising: each pixel having a photoelectric converting element (12) for generating a signal charge commensurate with a light-receiving amount, a floating diffusion part (18) for detecting an amount of a signal charge generated by the photoelectric converting element, a transfer transistor (16) for transferring a signal charge generated by the photoelectric converting element to the floating diffusion part, and a drain transistor (22) for draining a signal charge generated by the photoelectric converting element; a reset transistor (20) for resetting the floating diffusion part with a signal charge, and an amplifying transistor (24) for outputting an electric signal corresponding to a potential on the floating diffusion part, and a selecting transistor (28) for selectively activating the amplifying transistor; wherein the photoelectric converting element comprises a buried photodiode (Fig 8) having a charge separating region comprising a first conductivity type high-concentration impurity layer (Fig 8 item p) in an extreme surface of a semiconductor substrate and a charge storing region comprising a second conductivity type impurity layer (Fig 8 item n) in a layer beneath the charge separating region; both a channel potential on the drain transistor being turned on and a channel potential on the transfer transistor being turned on are set higher than a potential for depleting the photodiode (Fig 3B for transfer, Fig 3F for drain).

17. The claim language referring to the simultaneous resetting, simultaneous signal transfer, row by row signal read-out, and the fact that the drain transistor is kept on until the reading operation proceeds to a predetermined row, and is off during an operation

to read out the signal charge, describes an intended use of the device. Intended use and other types of functional language must result in a structural difference between the claimed invention and the prior art in order to patentably distinguish the claimed invention from the prior art. If the prior art structure is capable of performing the intended use, then it meets the claim. *In re Casey*, 152 USPQ 235 (CCPA 1967); *In re Otto*, 136 USPQ 458, 459 (CCPA 1963).

Claim Rejections - 35 USC § 103

18. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

19. **Claims 9 and 24 are rejected under 35 U.S.C. 103(a) as being unpatentable over Fox.** Fox discloses in Fig 3 an apparatus according to claims 2 and 17, wherein the transfer (16), reset (20) and select (28) transistor are driven on a pixel-row basis (col 5 In 1-7). Fox does not specify that the transfer, reset and select transistor gate wiring is provided in a row direction while the drain transistor (22) gate wiring is along the column direction, but does disclose that the drain transistor gate wiring is short-circuited together (see timing diagram Figs 4A and 4B). However, it is well known in the art that gate wiring for pixel transistors runs between pixels in either the row or column direction, to be driven by horizontal and vertical scanning circuits. Additionally, Fox discloses a timing diagram in Fig 4B, where the EC signal is held on a column while

each row is sampled (transfer, reset, select). It would have been obvious to one of ordinary skill in the art at the time of the invention to arrange the wiring of the transfer, reset and select transistors in the row direction, since they are driven on a row basis, while the drain transistor wiring is arranged along the column direction since it is driven in the vertical direction.

20. Claim 25 is rejected under 35 U.S.C. 103(a) as being unpatentable over Fox and Fossum (US 6,624,456). Fox discloses the apparatus of claim 16, but does not specify switch means for switching shutter operation of the imaging device between focal-plane shutter and all-pixel simultaneous shutter operation.

21. Fossum teaches that image sensors may be operated in two ways, one being the rolling shutter (or focal-plane shutter) mode, and the other being an all-pixel simultaneous operation (col 1 ln 12-24), depending on whether the application requires more time consistency. It would have been obvious to one of ordinary skill in the art at the time of the invention to use the teachings of Fossum on the apparatus of Fox depending on whether the application required more time consistency.

22. Claim 26 is rejected under 35 U.S.C. 103(a) as being unpatentable over Fox and applicant's admitted prior art (AAPA). Fox discloses the apparatus of claim 19, but does not specify exposure time selecting means for selecting an exposure time of the device and exposure start row selecting means for selecting the predetermined exposure start row depending on the exposure time selected by the exposure time. However, since Fox has a pixel that is fully depleted during charge transfers, the rows are capable of being selected based on a predetermined exposure time and exposure can be started

during readout of signals. It is well known in the art to include exposure time selecting means on cameras. AAPA recites that exposure had been impossible during a transfer duration over all the rows, and therefore exposure time could not be increased. Since Fox is capable of having exposure and readout occurring simultaneously, it would have been obvious to one of ordinary skill in the art at the time of the invention to include exposure time selecting means that select rows for exposure depending on an exposure time selected.

Response to Arguments

23. Applicant's arguments filed 7 July 2008 have been fully considered but they are not persuasive. Regarding the argument on page 12 that Fox does not disclose a device in which a bias voltage is applied to a transfer transistor and a drain transistor when the transistors are turned off, these limitations describe an intended use of the gate electrodes. Fox discloses that the transfer transistor (16) and drain transistor (22) have gate nodes (TCK and EC, respectively). Therefore, the gate nodes of Fox are capable of being biased, resulting in a first conductivity type channel layer at an interface of a gate insulation film of each transistor. Regarding the argument on page 13 that Fox resets the FD just after reading out rather than simultaneously resetting and reading, and that Fox teaches that the drain transistor is always on during a non-exposure time, these limitations describes the function and intended use of the structures disclosed. Intended use and other types of functional language must result in a structural difference between the claimed invention and the prior art in order to

patentably distinguish the claimed invention from the prior art. If the prior art structure is capable of performing the intended use, then it meets the claim. *In re Casey*, 152 USPQ 235 (CCPA 1967); *In re Otto*, 136 USPQ 458, 459 (CCPA 1963). In this case, the structure of Fox can have voltages applied to the gate electrodes of each transistor in order to perform the functions recited in the claims.

Conclusion

24. Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to JOHN C. INGHAM whose telephone number is (571)272-8793. The examiner can normally be reached on M-F, 8am-5pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Wael Fahmy can be reached on (571) 272-1705. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

/Howard Weiss/
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